Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady	$T_{C} = 25^{\circ}C$	Ι _D	87	А
Current $R_{\theta JC}$ (Notes 1, 3)		T _C = 100°C		61	
Power Dissipation	State	$T_{C} = 25^{\circ}C$	PD	55	W
R _{θJC} (Note 1)		$T_{C} = 100^{\circ}C$		27	
Continuous Drain		T _A = 25°C	Ι _D	22	А
Current R _{θJA} (Notes 1, 2, 3)	Steady State	T _A = 100°C		16	
Power Dissipation		T _A = 25°C	PD	3.6	W
$R_{\theta JA}$ (Notes 1 & 2)		T _A = 100°C		1.8	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	520	А
Operating Junction and Storage Temperature			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			۱ _S	61	А
Single Pulse Drain-to-Source Avalanche Energy $(I_{L(pk)} = 5 A)$			E _{AS}	202	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	2.7	°C/W
Junction-to-Ambient - Steady State (Note 2)	R_{\thetaJA}	42	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

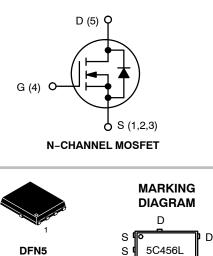
3. Maximum current for pulses as long as 1 second is higher but is dependent n pulse duration and duty cycle.

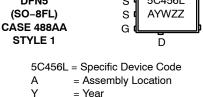


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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	$3.7~\mathrm{m}\Omega$ @ 10 V	07.4
40 V	6.0 mΩ @ 4.5 V	87 A





D

= Work Week

W = Lot Traceability ΖZ

ORDERING INFORMATION

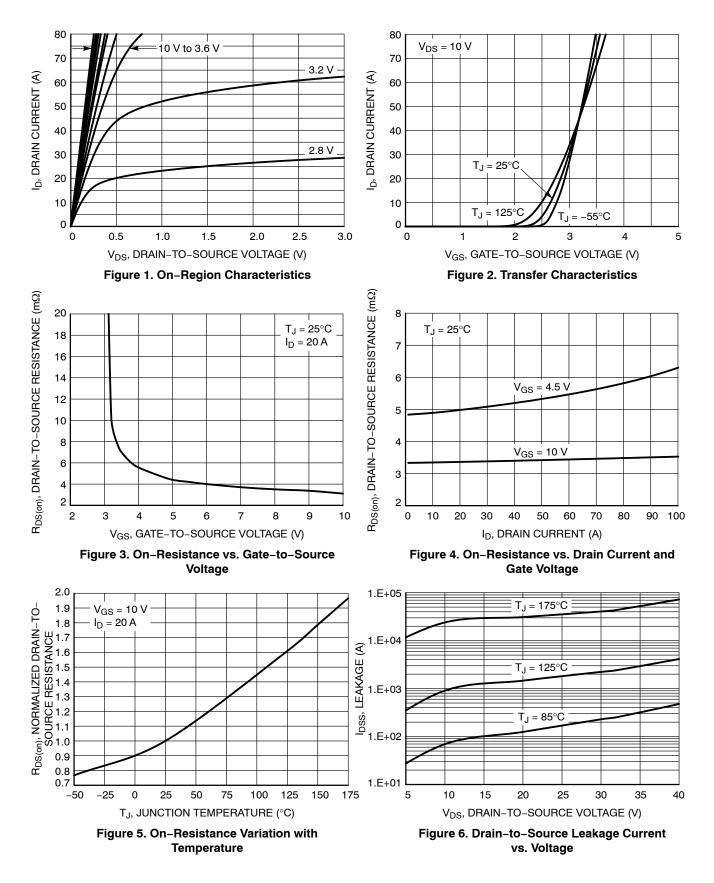
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

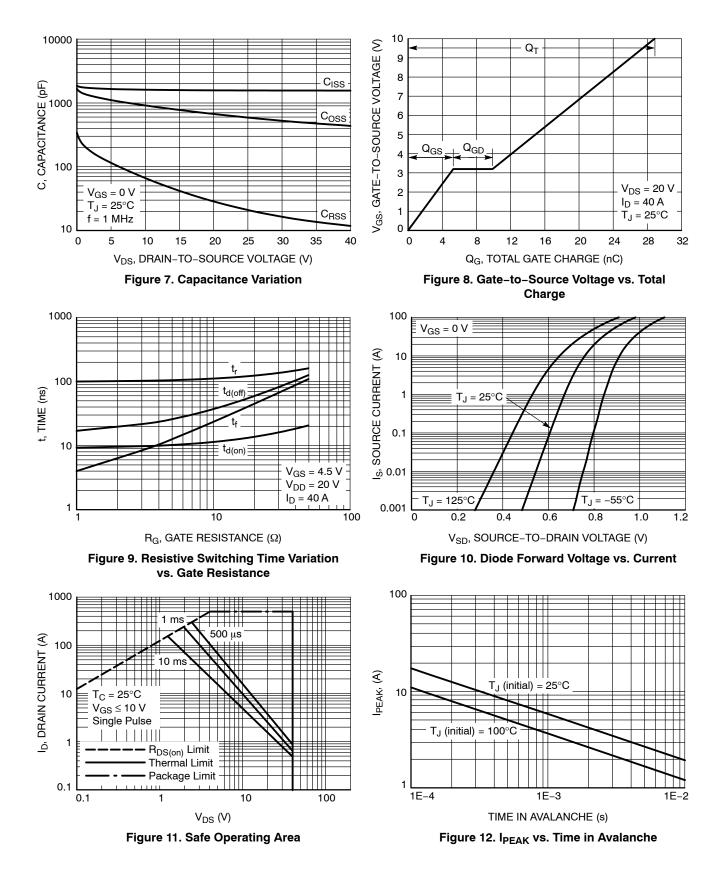
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				22		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25 °C			10	
		V _{DS} = 40 V	T _J = 125°C		μA 250		μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA
ON CHARACTERISTICS (Note 4)					-	-	-
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 50 \ \mu A$		1.2		2.0	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J	· · · · ·			-5.1		mV/°0
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A		3.1	3.7	
		V _{GS} = 4.5 V	I _D = 20 A		4.8	6.0	mΩ
Forward Transconductance	9 _{FS}	V _{DS} = 15 V, I _D = 40 A			80		S
CHARGES, CAPACITANCES & GATE RE	SISTANCE				•		
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 25 V			1600		pF
Output Capacitance	C _{OSS}				590		
Reverse Transfer Capacitance	C _{RSS}				21		
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 20 V; I_{D} = 40 A			28.8		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 4.5 V, V _{DS} = 20 V; I _D = 40 A			13.5		nC V
Threshold Gate Charge	Q _{G(TH)}				2.6		
Gate-to-Source Charge	Q _{GS}				5.3		
Gate-to-Drain Charge	Q _{GD}				4.9		
Plateau Voltage	V _{GP}				3.3		
SWITCHING CHARACTERISTICS (Note 5	5)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 4.5 V, V_{DS} = 20 V, I_{D} = 40 A, R_{G} = 1.0 Ω			9.3		
Rise Time	tr				100		ns
Turn-Off Delay Time	t _{d(OFF)}				17		
Fall Time	t _f				4.0		
DRAIN-SOURCE DIODE CHARACTERIS	TICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 40 A	T _J = 25°C		0.86	1.2	
			T _J = 125°C		0.75		V
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 40 A			29		
Charge Time	ta				14		ns
Discharge Time	t _b				15		1
Reverse Recovery Charge	Q _{RR}				20		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

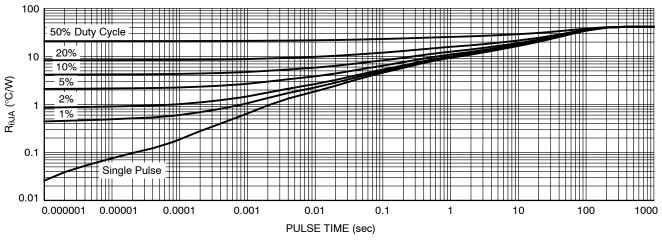


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS5C456NLT1G	5C456L	DFN5 (Pb–Free)	1500 / Tape & Reel
NTMFS5C456NLT3G	5C456L	DFN5 (Pb–Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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